

TESDV5V0A Steering Diode Structure ESD Protection Array

Small Signal Diode



Features

- ♦Meet IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- ♦Meet IEC61000-4-4 (EFT) rating. 40A (5/50ήs)
- ♦Protects four high speed I/O lines
- ♦Working Voltage : 5V
- ♦Pb free version, RoHS compliant, and Halogen free

Mechanical Data

- ♦ Case: SOT-363 standard package, molded plastic
- →Terminal: Matte tin plated, lead free, solderable per MIL-STD-202, Method 202 guaranteed
- ♦High temperature soldering guaranteed: 260°C/10s
- ♦ Molding Compound Flammability Rating: UL 94V-O
- ♦Weight :8 mg (approximately)
- ♦Marking Code : B54

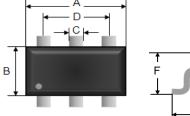
Applications

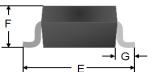
- ♦USB Power & Data Line Protection
- ♦Notebooks, Desktops, Servers and Video Graphics Cards
- ♦Monitors and Flat Panel Displays
- ♦Set Top Box

Ordering Information

Part No.	Package	Packing	Packing Code	Marking
TESDV5V0A	SOT-363	3K / 7" Reel	RFG	B54

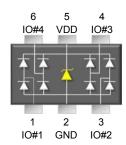
SOT-363





Dimensions	Unit (mm)		Unit (inch)	
Difficusions	Min	Max	Min	Max
Α	1.80	2.00	0.071	0.079
В	1.15	1.35	0.045	0.053
С	0.15	0.30	0.006	0.012
D	1.30 BSC		0.051 BSC	
E	2.10 BSC		0.083 BSC	
F	-	1.10	-	0.043
G	0.42		0.017	

Pin Configutation



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Maximum Ratings

Type Number	Symbol	Value	Units
Peak Pulse Power (tp=8/20µs waveform)	P _{PP}	150	W
Peak Pulse Current (tp = 8/20μs)	I PP	3	Α
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	±16 ±8	KV
Junction and Storage Temperature Range	TJ, Tsтg	-55 to + 150	°C

Electrical Characteristics

Type Number		Symbol	Min	Max	Units
Reverse Stand-Off Voltage		V_{RWM}	-	5	V
Reverse Breakdown Voltag	I _R = 1mA	$V_{(BR)}$	6	-	V
Reverse Leakage Current	V _R = 5V	lπ	-	1	uA
Clamping Voltage	I _{PP} = 1A	Vc	-	15	V
	I _{PP} = 3A	VC	-	25	<u> </u>
Junction Capacitance	V _R =0V, f=1.0MHz	Сл	2 (T	yp.)	pF



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Rating and Characteristic Curves

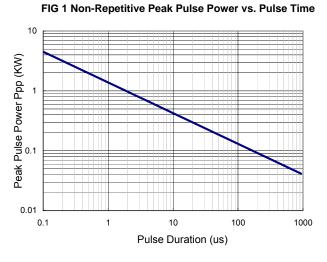


FIG 2 Pulse Waveform

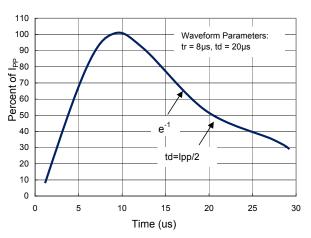


FIG 3 Admissible Power Dissipation Curve

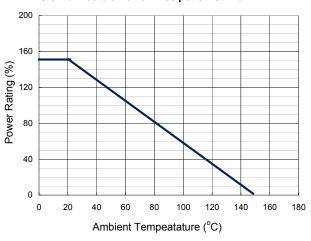


FIG 4 Typical Junction Capacitance

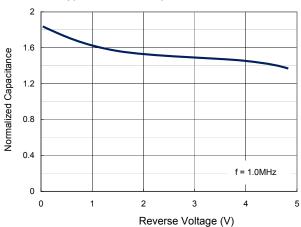
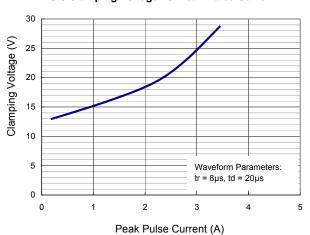


FIG 5 Clamping Voltage vs. Peak Pulse Current



Version : A11



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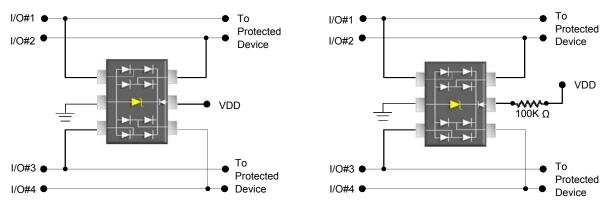
Applications Information

- ♦Designed to protect protect high speed data interfaces
- ♦ Designed to protect four data lines from transient over-voltages by clamping them to a fixed reference
- ♦ Designed to protect protect sensitive components which are connected to data and transmission lines from overvoltage caused by electrostatic discharge (ESD), electrical fast transients (EFT), and lightning.
- ♦TESDS5V0ALC incorporates eight surge rated, low capacitance steering diodes and a TVS diode in a single package
- ♦ During transient conditions, the steering diodes direct the transient to either the positive side of the power supply line or to ground
- ♦The internal TVS diode prevents over-voltage on the power line, protecting any downstream components

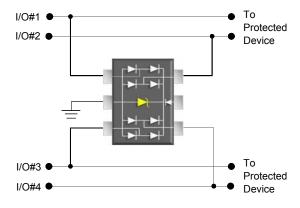
Circuit Board Layout Recommendations

- ♦To protect data lines and the power line, connect pin 5 directly to the VDD. In this configuration the data lines are referenced to the supply voltage. The internal TVS diode prevents over-voltage on the supply rail.
- \$\times The TESDS5V0ALC can be isolated from the power supply by adding a series resistor between pin 5 and VDD. A value of 100kΩ is recommended. The internal TVS and steering diodes remain biased, providing the advantage of lower capacitance.

²In applications where no positive supply reference is available, or complete supply isolation is desired, the internal TVS may be used as the reference. In this case, pin 5 is not connected. The steering diodes will begin to conduct when the voltage



- ♦Data Line and Power Supply Protection Using Vcc as reference
- ♦Data Line Protection with Bias and Power Supply Isolation



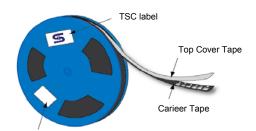
♦Data Line Protection Using Internal TVS Diode as Reference



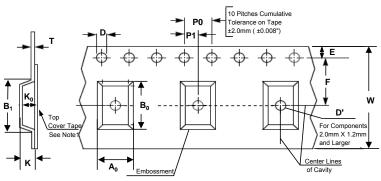
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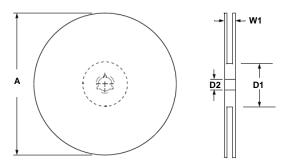
Tape & Reel specification



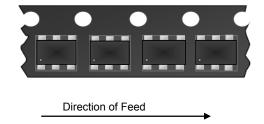
Any Additional Label (If Required)



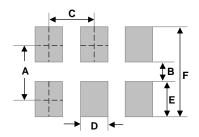
For Machine Reference Only Including Draft and RADLL Concentric Around B₀



Item	Symbol	Dimension (mm)
Carrier depth	K	1.22 Max.
Sprocket hole	D	1.50 +0.10
Reel outside diameter	Α	180 ± 1
Reel inner diameter	D1	50 Min.
Feed hole width	D2	13.0 ± 0.5
Sprocke hole position	Е	1.75 ±0.10
Sprocke hole pitch	P0	4.00 ±0.10
Embossment center	P1	2.00 ±0.10
Overall tape thickness	Т	0.6 Max.
Tape width	W	8.30 Max.
Reel width	W1	14.4 Max.



Suggested PAD Layout



Dimensions	Unit (inch)	Unit (mm)
Α	0.073	1.85
В	0.039	1.00
С	0.026	0.65
D	0.016	0.40
E	0.033	0.85
F	0.106	2.70

Note 1: A_0 , B_0 , and K_0 are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min. to 0.5 mm max. The component cannot rote more than 10 ° within the determined cavity.

Note 2: If B₁ exceeds 4.2 mm(0.165") for 8 mm embossed tape, the tape may not feed through all tape feeders.

Note 3: The suggested land pattern dimensions have been provided for reference only, as actual pad layouts may vary despending on application.